Thyristor Semiconductor Device - Page 1 of 1



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Inclosure Material:

Metal

**Overall Length:** 

0.359 inches

**Overall Diameter:** 

0.875 inches

**Mounting Facility Quantity:** 

2

## **Internal Configuration:**

Junction contact

**Mounting Method:** 

Unthreaded hole

Features Provided:

Hermetically sealed case

**Semiconductor Material:** 

Silicon

## Voltage Rating In Volts Per Characteristic:

400.0 breakover voltage, dc

## **Current Rating Per Characteristic:**

25.00 amperes source cutoff current

# Power Rating Per Characteristic:

0.5 watts small-signal input power, common-collector blank

## Maximum Operating Tempurature Per Measurement Point:

125.0 degrees celsius junction

**Special Features:** 

Collector connected to case; junction pattern arrangement: pnpn

# Terminal Type And Quantity:

2 tab, solder lug and 1 case

Shelf Life:

N/a

# Unit Of Measure:

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# Demilitarization:

No

## Fiig:

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